

Switchmode Dual Ultrafast Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- * High Surge Capacity
- *Low Power Loss, High efficiency
- * Glass Passivated chip junctions
- ★150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage , High Current Capability
- *High-Switching Speed 35 Nanosecond Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- Flammability Classification 94V-O
- * Pb free

* In compliance with EU RoHs directives



MAXIMUM RATINGS

Characteristic	Symbol	UE20C20C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
RMS Reverse Voltage	V _{R(RMS)}	140	V
Average Rectifier Forward Current Total Device (Rated V _R)	I _{F(AV)}	10 20	A
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	200	А
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

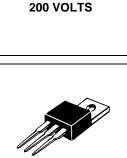
ELECTRICAL CHARACTERISTICS

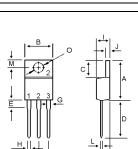
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage (I _F =10 Amp T _C = 25℃) (I _F =10 Amp T _C = 125℃)	V _F		0.910 0.780	0.975	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25℃) (Rated DC Voltage, T _C = 125℃)	I _R		0.01 5	10 	uA
Reverse Recovery Time (I_F = 0.5 A, I_R =1.0 , I_{rr} =0.25 A)	Trr		17	35	ns
Typical Thermal Resistance junction to case	$R_{\theta jc}$		3.4		°C/w
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	CP		65		₽F

UE20C20C

ULTRA FAST RECTIFIERS

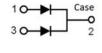
20 AMPERES





TO-220AB

DIM	MILLIMETERS			
DIN	MIN	MAX		
Α	14.68	16.00		
В	9.78	10.42		
С	5.02	6.60		
D	13.00	14.62		
E	3.10	4.19		
F	2.41	2.67		
G	1.10	1.67		
н	0.69	1.01		
I	4.22	4.98		
J	1.14	1.40		
К	2.20	3.30		
L	0.28	0.61		
Μ	2.48	3.00		
0	3.50	4.00		





UE20C20C

FIG-3 FORWARD CURRENT DERATING CURVE

20

16

12

8

4

0 L 0

180

25

50

75

LEAD TEMPERATURE (°C)

FIG-4TYPICAL JUNCTION CAPACITANCE

100

125

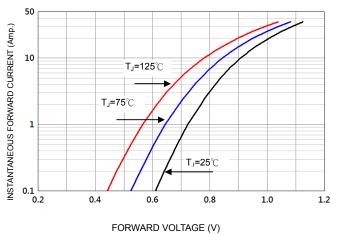
150

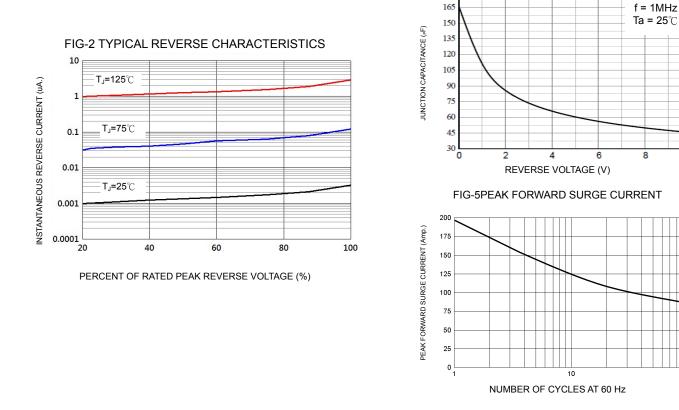
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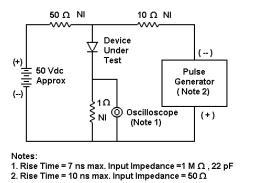
100

AVERAGE FORWARD RECTIFIED CURRENT (Amp.)

FIG-1 TYPICAL FORWARD CHARACTERISTICS







Set time base for 10/20 ns/cm

Set time base for 10/20

t,,

+0.54

0

-0.25A

-1.0A

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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